

Form PTO-1449					ATTY. DOCKET NO. 1215-0485P(000277-078)		APPLICATION NO. 10/648,206		
INFORMATION DISCLOSURE CITATION IN AN APPLICATION <small>(Use several sheets if necessary)</small>					APPLICANT Alfred P. TURLEY				
					FILING DATE August 27, 2003		GROUP 2811		
U.S. PATENT DOCUMENTS									
EXAMINER INITIAL	DOCUMENT NUMBER	Kind	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE		
Loke	US 2001/0008284	A1	2001-07-19	HUANG					
Loke	US 2002/0053705	A1	2002-05-09	Kondo et al.					
Loke	US 2002/0142558	A1	2002-10-03	Hsu					
Loke	US 2003/0057487	A1	2003-03-27	Yamada et al.					
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FOREIGN PATENT DOCUMENTS									
	Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION	
								YES	NO
OTHER DOCUMENTS <small>(Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.)</small>									
Loke	"A 3-D BiCMOS Technology Using Selective Epitaxial Growth (SEG) and Lateral Solid Phase Epitaxy (LSPE)", Kumar et al., International Electron Devices Meeting, 2001, Technical Digest, Washington, D.C. December 2-5, 2001, New York, New York; IEEE, US December 2, 2001, pages 729-732								
EXAMINER <div style="text-align: center; font-size: 1.2em;">Loke</div>					DATE CONSIDERED <div style="text-align: center; font-size: 1.2em;">10/29/04</div>				
<small>EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.S.P. 201; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</small>									